



Complementary 20 V (D-S) Low-Threshold MOSFET

PRODUCT SUMMARY							
	V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)				
		0.280 at $V_{GS} = 4.5 \text{ V}$	1.28				
N-Channel	20	0.360 at V _{GS} = 2.5 V	1.13				
		0.450 at V _{GS} = 1.8 V	1				
		$0.490 \text{ at V}_{GS} = -4.5 \text{ V}$	- 1				
P-Channel	- 20	0.750 at V _{GS} = - 2.5 V	- 0.81				
		1.10 at V _{GS} = - 1.8 V	- 0.67				

FEATURES

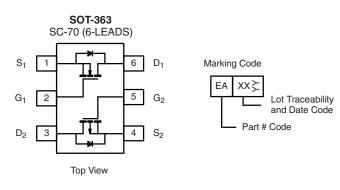
- TrenchFET® Power MOSFETS: 1.8 V Rated
- ESD Protected: 2000 V
- Thermally Enhanced SC-70 Package
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

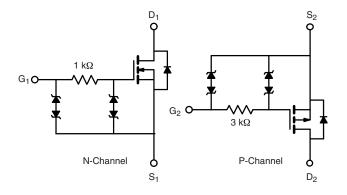


HALOGEN **FREE**

APPLICATIONS

- Load Switching
- PA Switch
- Level Switch





Ordering Information: Si1563EDH-T1-E3 (Lead (Pb)-free)

Si1563EDH-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)							
			N-Channel		P-Channel		
Parameter		Symbol	5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	20		- 20		V
Gate-Source Voltage		V_{GS}	± 12		± 12		v
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	- I _D	1.28	1.13	- 1	- 0.88	_
	T _A = 85 °C		0.92	0.81	- 0.72	- 0.63	
Pulsed Drain Current		I _{DM}		4	- 3		A
Continuous Source Current (Diode Conduction) ^a		I _S	0.61	0.48	- 0.61	- 0.48	
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	0.74	0.57	0.30	0.57	W
	T _A = 85 °C		0.38	0.30	0.16	0.3	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^a	t ≤ 5 s	В	130	170			
Waximum Junction-to-Ambient	Steady State	R_{thJA}	170	220	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	80	100			

a. Surface mounted on 1" x 1" FR4 board.



Parameter Symbol		Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage		$V_{DS} = V_{GS}, I_D = 100 \mu A$	N-Ch	0.45		1	V	
	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 100 μA	P-Ch	- 0.45		- 1		
Gate-Body Leakage	I _{GSS}		N-Ch			± 1	μA - mA	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$	P-Ch			± 1		
		V 0VV 110V	N-Ch			± 10		
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$	P-Ch			± 10		
		V _{DS} = 16 V, V _{GS} = 0 V	N-Ch			1	μΑ	
Zana Oata Wallana Busin Oursel		V _{DS} = - 16 V, V _{GS} = 0 V	P-Ch			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 16 V, V _{GS} = 0 V, T _J = 85 °C	N-Ch			5		
		V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 85 °C	P-Ch		- 5	1		
On-State Drain Current ^a		$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	N-Ch	2			Α	
	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	P-Ch	- 2				
Drain-Source On-State Resistance ^a		V _{GS} = 4.5 V, I _D = 1.13 A	N-Ch		0.220	0.280		
		V _{GS} = - 4.5 V, I _D = - 0.88 A	P-Ch		0.400	0.490		
	R _{DS(on)}	V _{GS} = 2.5 V, I _D = 0.99 A	N-Ch		0.281	0.360	Ω	
		V _{GS} = - 2.5 V, I _D = - 0.71 A	P-Ch		0.610	0.750		
		V _{GS} = 1.8 V, I _D = 0.20 A	N-Ch		0.344	0.450		
		V _{GS} = - 1.8 V, I _D = - 0.20 A	P-Ch		0.850	1.10		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 1.13 A	N-Ch		2.6		S	
		V _{DS} = - 10 V, I _D = - 0.88 A	P-Ch		1.5			
Die de Ferrand Velle and	V _{SD}	I _S = 0.48 V, V _{GS} = 0 V	N-Ch		0.8	1.2	V	
Diode Forward Voltage ^a		I _S = - 0.48 V, V _{GS} = 0 V	P-Ch		- 0.8	- 1.2		
Dynamic ^b	•							
Tatal Cata Chausa			N-Ch		0.65	1		
Total Gate Charge	Q_g	N-Channel	P-Ch		1.2	1.8	nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1.13 \text{ A}$	N-Ch		0.2			
		P-Channel	P-Ch		0.3			
Gate-Drain Charge	Q_{gd}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -0.88 \text{ A}$	N-Ch		0.23			
			P-Ch		0.3			
Turn-On Delay Time	t _{d(on)}		N-Ch		45	70		
		N-Channel	P-Ch		150	230	ns	
Rise Time	t _r	$V_{DD} = 10 \text{ V, R}_{L} = 20 \Omega$	N-Ch		85	130		
		$I_D \cong 0.5 A$, $V_{GEN} = 4.5 V$, $R_g = 6 \Omega$	P-Ch		480	720		
Turn-Off Delay Time	t _{d(off)}	P-Channel	N-Ch		350	530		
		V_{DD} = - 10 V, R_L = 20 Ω	P-Ch		840	1200		
E 11.7:		$I_D \cong -0.5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 6 \Omega$	N-Ch		210	320		
Fall Time	t _f		P-Ch		850	1200		

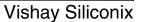
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

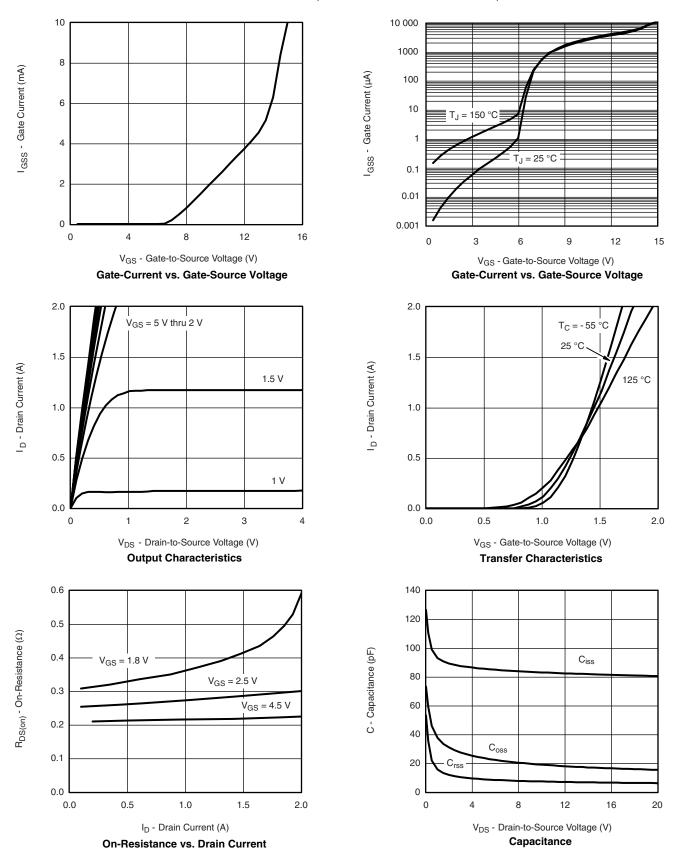
b. Guaranteed by design, not subject to production testing.



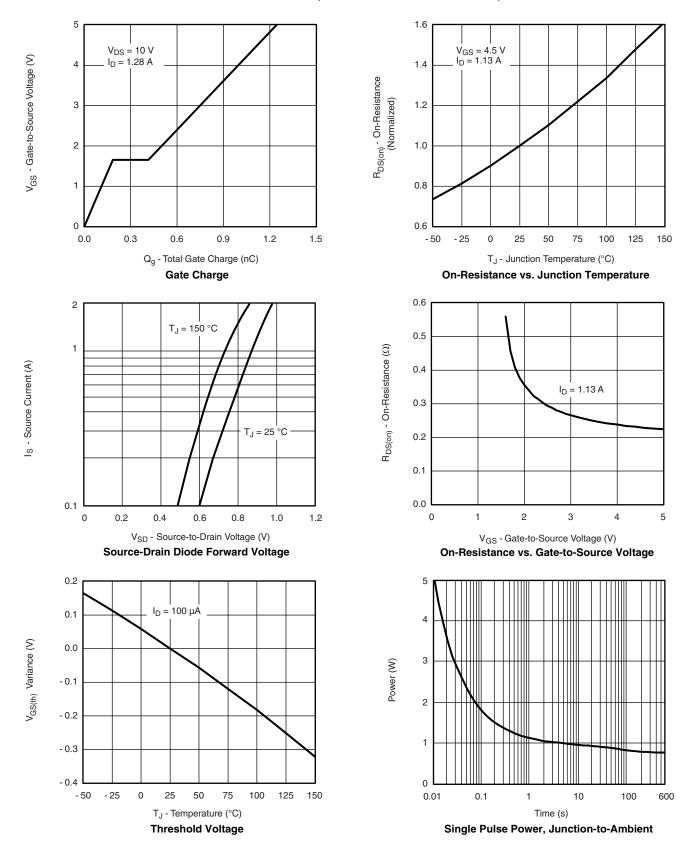




N-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

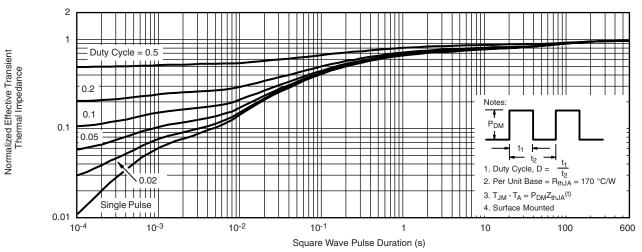


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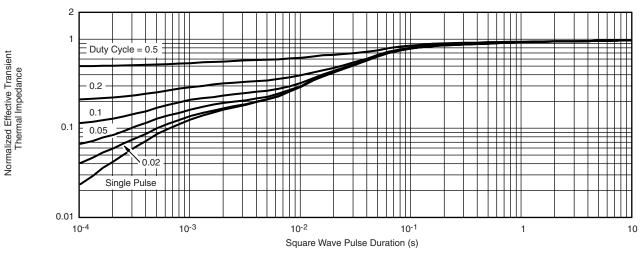




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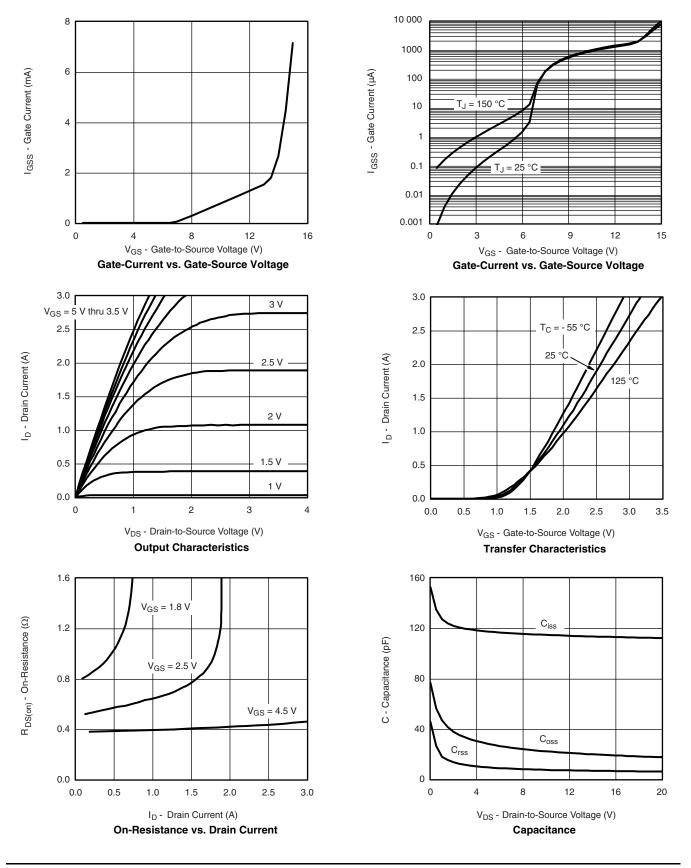
Normalized Thermal Transient Impedance, Junction-to-Ambient



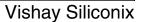
Normalized Thermal Transient Impedance, Junction-to-Foot



P-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

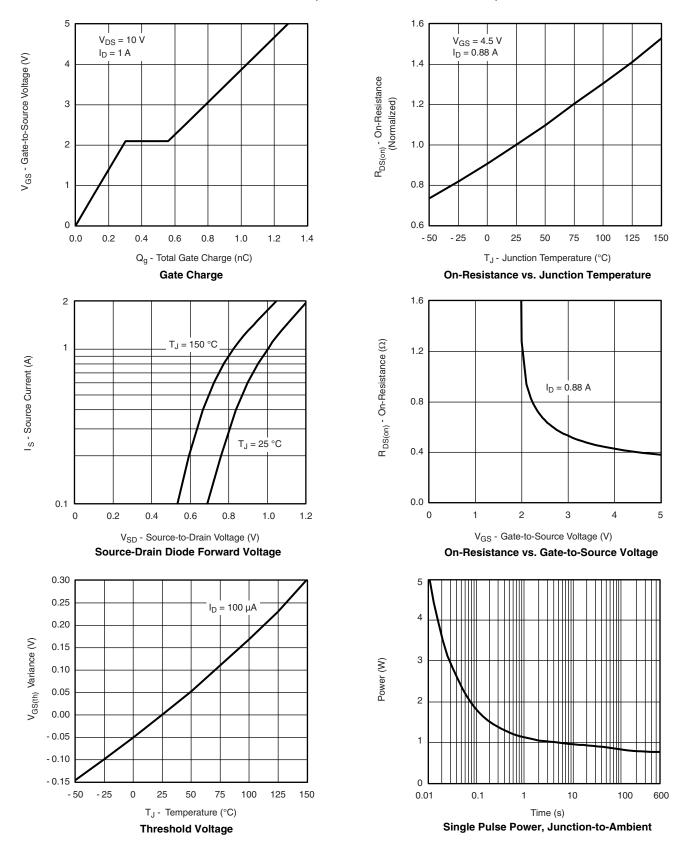






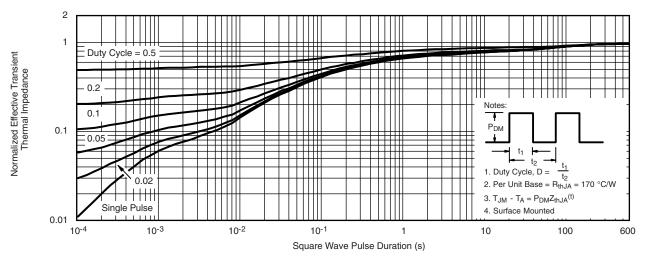


P-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

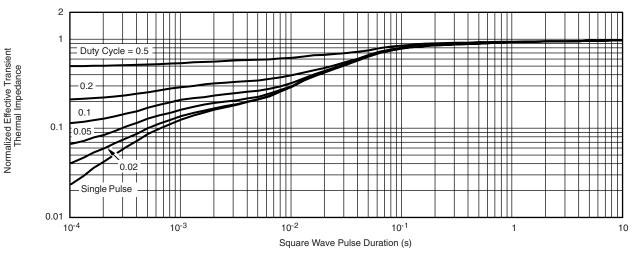




P-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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